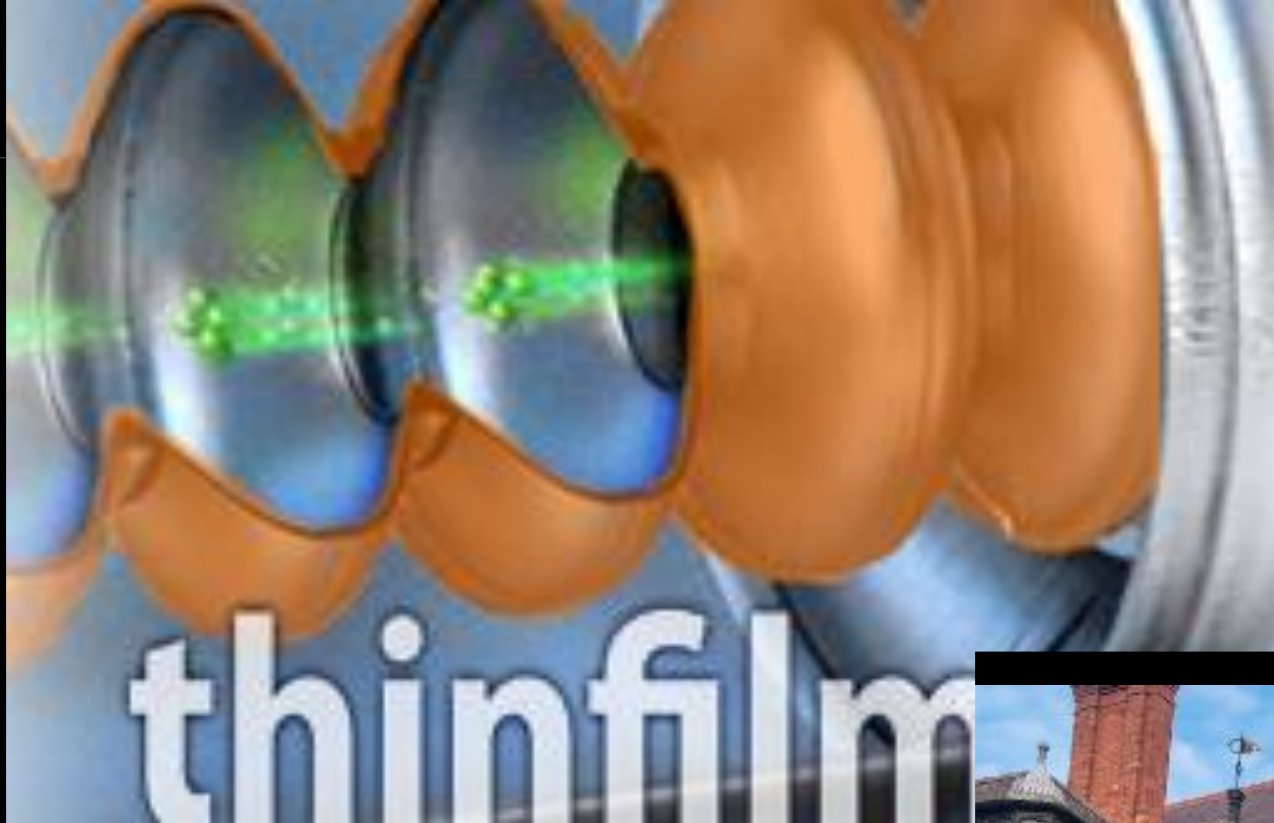




WELCOME

TFSRF 2026- 12th EDITION

THIN FILM AND NEW IDEAS FOR PUSHING THE LIMITS OF RF SUPERCONDUCTIVITY

International Organising Committee:

Anne- Marie Valente

Alex Gurevich

Reza Valizadeh - Chair

Cristian Pira

Thomas Proslie

Walter Venturini Delsolaro

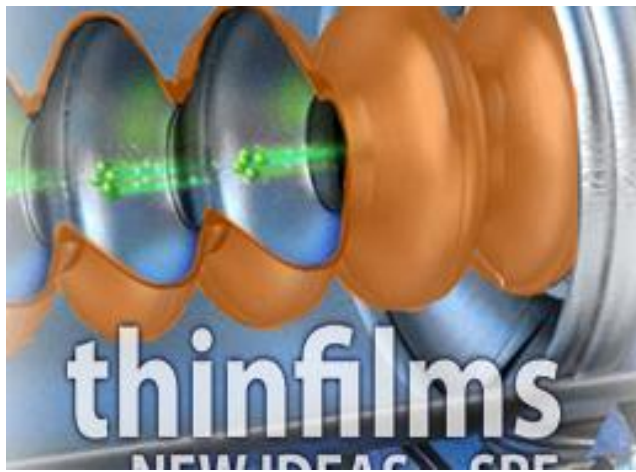
Takayuki Saeki



The TFSRF Started in 2005 at JLab

- Has been alternatively every 2 years by Jlab and INFN Legnaro (except 2020)
- From 2024 edition
 - It is organized to be shared among other community
 - We propose to work at International level combining various road maps.
 - Intensify R&D and accelerate the progress in TF SRF field.

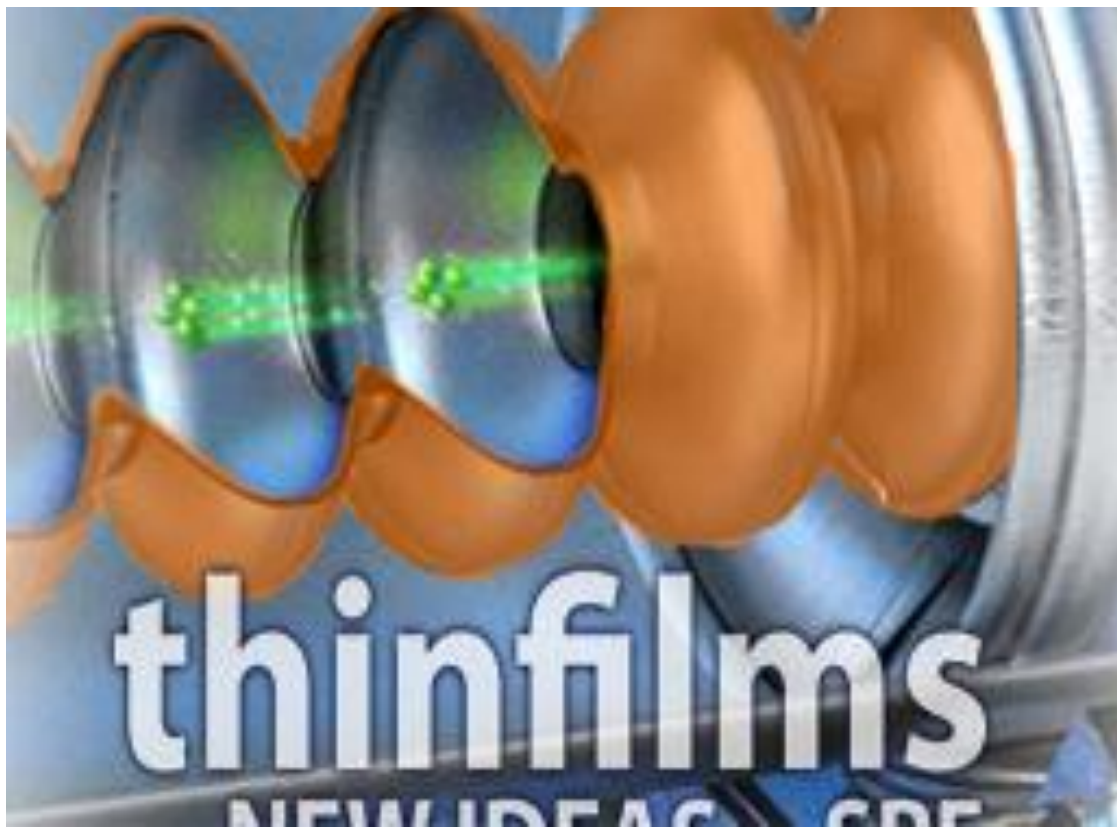




Sharing Ideas to create Synergy

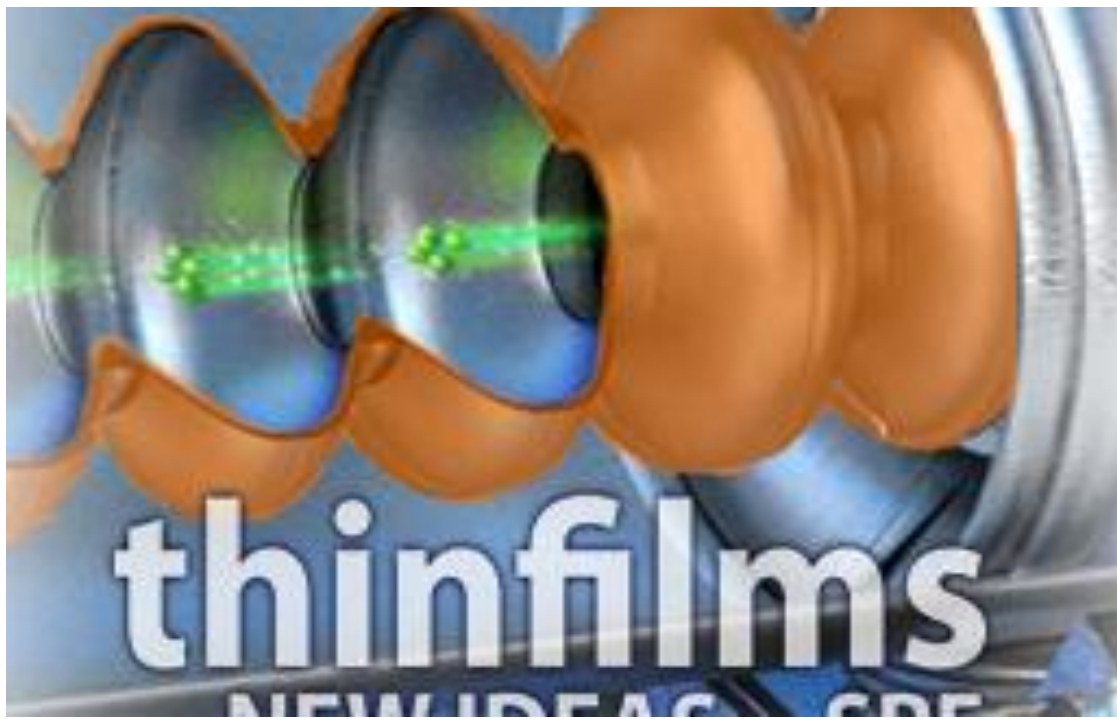
The primary aim of the workshop is to provide a collaborative environment as **open**, **inclusive** and **diverse** as possible, to foster **discussion** and **new ideas**.

- Setting the Horizon: Global Perspectives & Technical Roadmaps
- Pushing SRF Thin Films Limits: Theoretical Advances, Deposition Modeling & DFT
- Latest Advances in Nb Thin Film Technology
- Conventional PVD, energetic condensation from highly ionized plasmas
- Nb₃Sn Technology: Recent Technical Advances & Scaling Horizons
- Beyond Nb & Nb₃Sn: Alternate materials, multilayer SIS structures and functional layers
- Tailored Substrates for Advanced Film Growth
- Emerging Frontlines in Characterization Methods: Advanced Imaging & Novel Probes
- Emerging Frontiers & Synergies in SRF Thin Films: From Quantum Sensing to AI-Driven Material



Speakers

Please upload your slides the day BEFORE your talk, we need to download them in order to verify them and show on ZOOM if needed

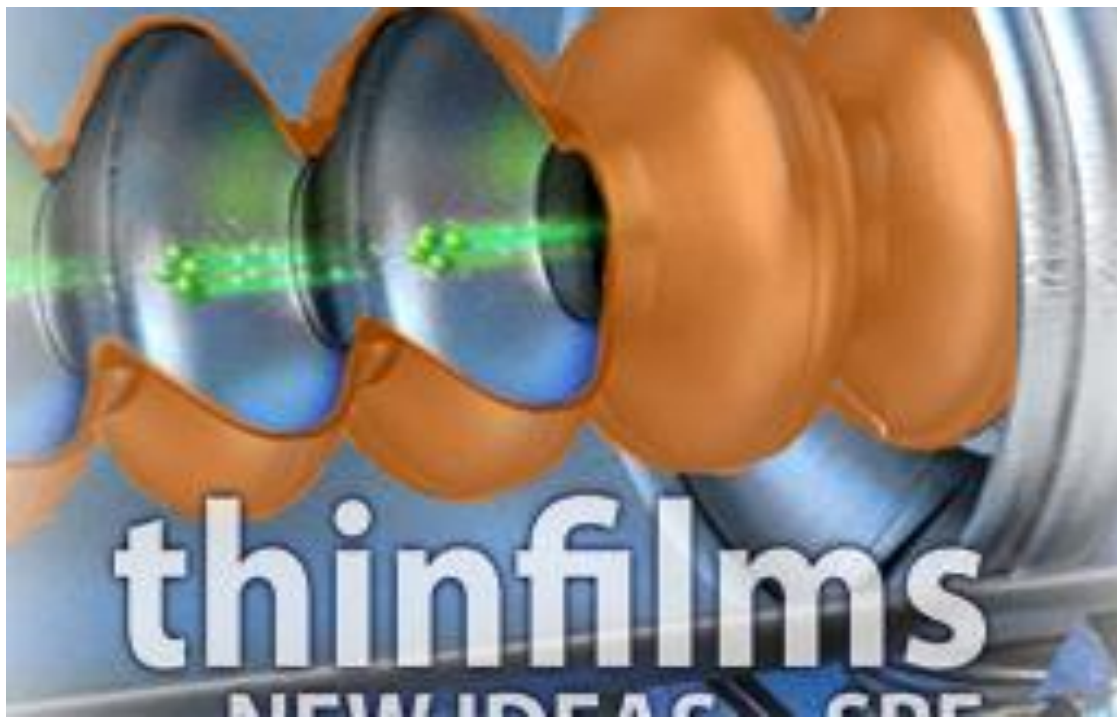


For those who are staying at the Plaza Hotel

Breakfast is included

Lunch is served at restaurant adjacent .

For Dinner there will be plenty of choices in city centre



Visit to Daresbury Laboratory:

- A dedicated bus is arranged to take all the delegates to Lab and back.
- The bus will leave from the Hotel at 2:00 pm just after the lunch on Wednesday

Workshop Dinner



**Date: 23rd September
2026**

Time: 7pm

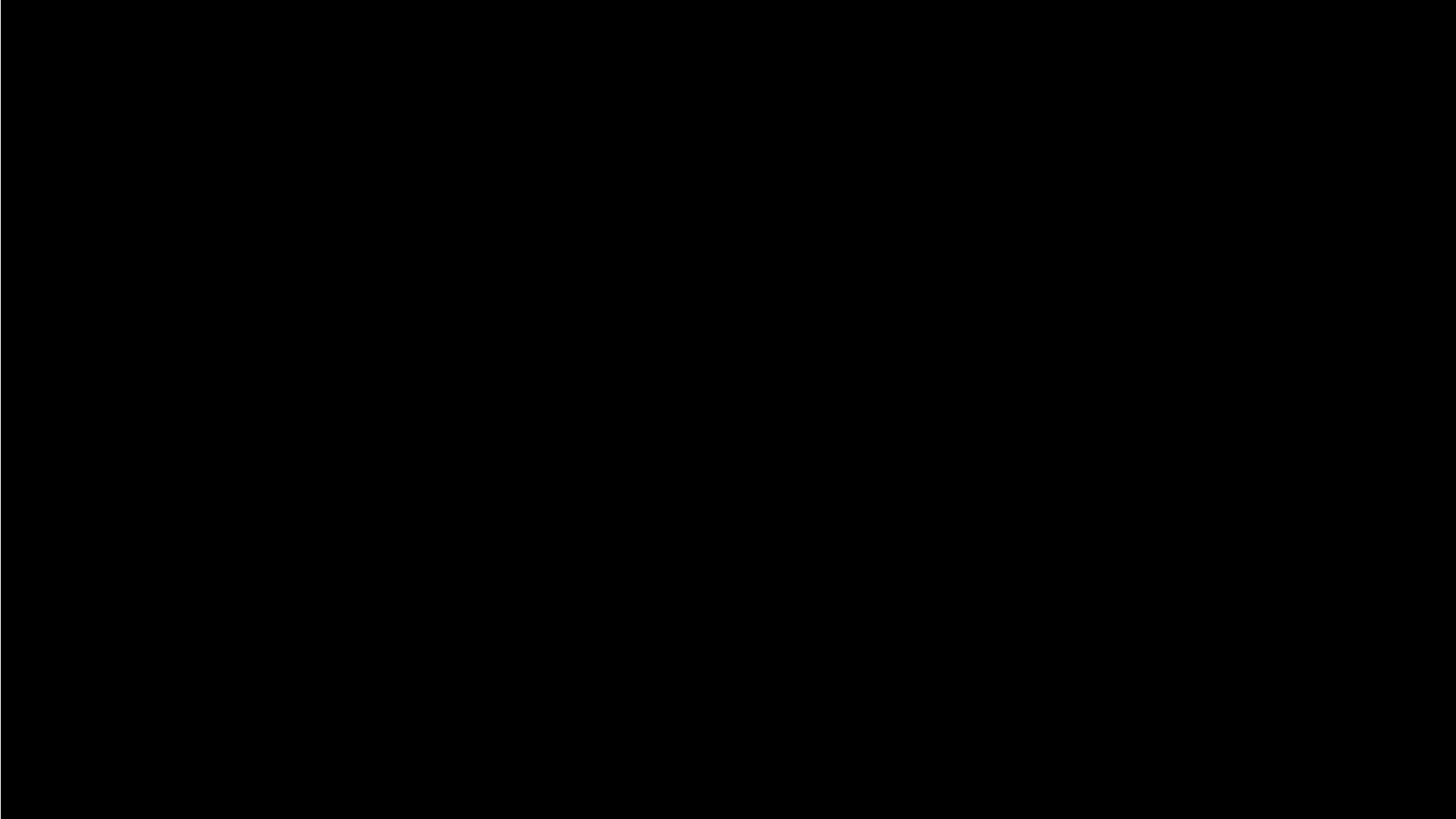
Chester Cathedral

Direction:

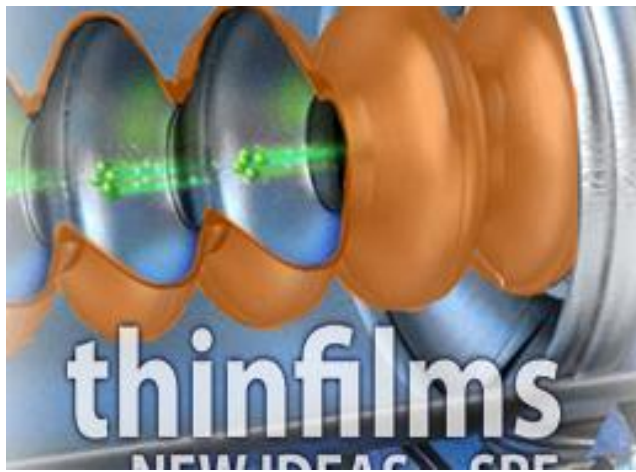
**5 minutes walk from
the Plaza Hotel,
Signed Posted.**



Remembering Abscent Colleagues

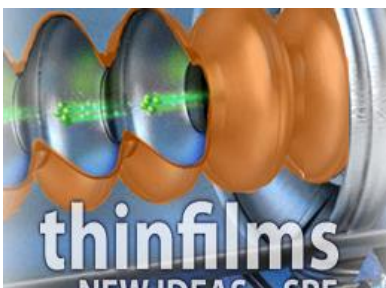


Science and
Technology
Facilities Council



Thin-Film Superconductivity for SRF Cavities

Current Status & Future Challenges

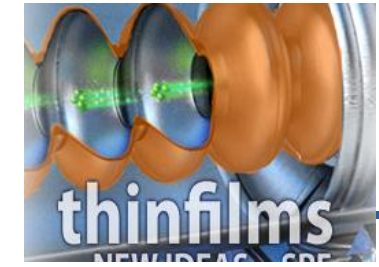


Why Thin Films for SRF?

- SRF performance is a SURFACE phenomenon — RF penetrates only ~ 40 nm (Nb) to ~ 350 nm (NbN)
- Bulk Nb is near its intrinsic limit (~ 50 MV/m) after decades of N-doping & processing

Thin films offer:

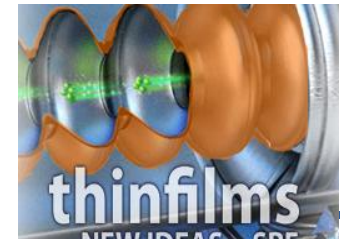
- Higher gradient potential (Nb₃Sn, multilayers)
- Operation at 4.2 K (vs 2 K for Nb) -> cheaper cryogenics
- Lower material cost (less Nb, Cu substrate)
- Better thermal stability (Cu's high thermal conductivity)
- Only the first few hundred nm 'matter' — the bulk is redundant



The Materials Landscape

Nb (sputtered on Cu) — Tc 9.2 K — Deployed (HIE-ISOLDE) — Mature
Nb₃Sn (A15) — Tc 18 K — Prototype cavities — Most optimised alternative

- NbN / NbTiN — Tc 16-17 K — Sample + small cavity — Mid-stage
- MgB₂ — Tc 39 K — Sample only — Exploratory
- Nb₃Al, V₃Si, Mo-Re — Tc 11-19 K — Sample studies — Exploratory
- SIS multilayers — Concept + samples — Early R&D
- Nb remains the benchmark. Nb₃Sn is the clear frontrunner among alternatives.



Status: Sputtered Nb on Cu

ACHIEVEMENTS

- CERN HIE-ISOLDE quarter-wave cavities: >60 MV/m surface peak field, $Q \sim 1e9$ at 2.3 K
- First production thin-film cavity to match bulk-Nb performance
- Seamless spun-Cu substrates eliminated weld-seam limitations
- 4 cryomodules (20 cavities) installed and operational

REMAINING LIMITS

- Voids, impurities, non-uniformity, adhesion issues
- Large elliptical cavities still trail bulk Nb

Status: Nb₃Sn — The Leading Alternative

- $T_c \sim 18 \text{ K}$ -> can operate at 4.2 K (no superfluid helium)
- Theoretical gradient $\sim 2 \times \text{Nb}$
- Single-cell: $Q_0 \sim 1 \times 10^{10}$ at $\sim 10 \text{ MV/m}$; up to 3×10^{10} at 2 MV/m (4.2 K)
- Coating methods: tin vapour diffusion, magnetron sputtering (DCMS, HiPIMS)

KNOWN PROBLEMS

- Sn deficiency / non-stoichiometric A15 phase
- Cu interdiffusion (on Cu substrate)
- Surface roughness -> major gradient limiter (Cornell)
- Film cracking under mechanical strain (brittle)
- Q-slope at high field

Status: Other Materials

Nitrides (NbN, NbTiN):

- Higher H_c than Nb, but high-field Q-slope & impurity incorporation limit performance

MgB₂:

- Highest T_c (~39 K) -> could operate at 15-20 K; but unstable, oxygen-sensitive

SIS multilayers (Superconductor-Insulator-Superconductor):

- Theoretical path to exceed Nb superheating field (>50 MV/m)
- Requires pinhole-free insulating layers — not yet at cavity scale

Key Achievements Summary

WHAT WORKS TODAY

- Thin-film Nb-on-Cu deployed in HIE-ISOLDE (production)
- Nb₃Sn demonstrates high Q at 4.2 K (prototype)
- Sample-level characterisation infrastructure mature
- European Thin-Film SRF Roadmap published (2025)
- Active international collaboration (CERN, Fermilab, Cornell, JLab, KEK, STFC)

WHAT DOES NOT YET WORK

- Reproducible high-gradient Nb₃Sn at production scale
- Thin films matching bulk-Nb gradient on large elliptical cavities
- Multilayer/SIS at cavity scale
- Stable MgB₂ coatings

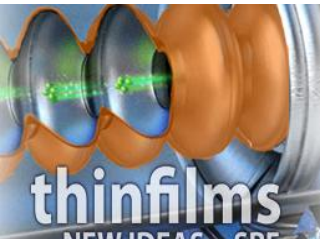
Challenge 1: Reproducibility & Yield

THE CHALLENGE

- Prototype cavities hit target performance; production runs do not
- Coating uniformity over complex cavity geometry is inconsistent
- Defect statistics not yet controlled enough for accelerator-grade yield

IMPACT

- Thin films cannot be specified for future machines (FCC, ILC) until yield is predictable
- *'A single great cavity is a paper. A hundred great cavities is a technology.'*



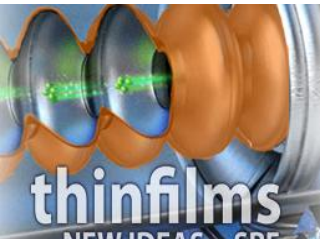
Challenge 2: Defects, Stoichiometry & Interface

Nb₃Sn-specific:

- A15 phase requires exact 3:1 Sn:Nb stoichiometry — deviations kill performance
- Sn-poor regions, voids, Cu interdiffusion create weak spots
- Surface roughness nucleates vortex entry -> premature quench

General:

- Particulates and pinholes -> field emission
- Film-substrate adhesion & thermal interface resistance -> hot spots, quench
- Impurity incorporation during sputtering (O, N, Ar)
- Coating chemistry & microstructure must be controlled to nm precision over m² of surface



Challenge 3: Mechanical & Operational Robustness

MECHANICAL

- Nb₃Sn is brittle — cracks under handling, cooldown thermal contraction, tuning stress
- Safe strain range is narrow ($\sim -2.3\%$ to $+0.9\%$)
- Recoating/healing degraded cavities is an active research area

OPERATIONAL

- Q-slope at high field limits useful gradient
- Flux pinning and trapped flux losses (especially at 4.2 K)
- Long-term field emission & gradient degradation in operation (LEP-II experience)

SCALING TO REAL CAVITIES

- Most data is from sample-level or single-cell tests
- Multi-cell, full-size elliptical cavities remain rare
- Cryomodule integration largely unproven for alternatives

NEW ARCHITECTURES NEEDED

- HiPIMS / energetic sputtering -> denser, void-free films
- Multilayer SIS -> break the Nb superheating-field limit
- In-situ surface preparation compatible with coating

EUROPEAN PROGRAMME CHAIN (Horizon 2020 / Europe)

- ARIES (2017-2021) WP15: substrate prep & TF quality (Nb, NbN, NbTiN, Nb₃Sn, SIS) — TRL 3
- IFAST (2021-2025) WP9: 6 & 1.3 GHz cavities; first bulk-Nb cavity PVD-coated with Nb₃Sn; EU TF-SRF roadmap; laser & FLA annealing — TRL 4-5
- iSAS (2024-2028) WP3: Cu cavities + Nb₃Sn coating & RF testing; flux trapping & mitigation; tunability
- EPITA (2027-2031) WP4: industrialise Nb₃Sn cavity production; vertical & horizontal cryostat tests; conduction cooling — TRL 6
- *Industrial partners: 0 (ARIES) -> 3-5 (EPITA); goal: transfer Nb₃Sn production to industry*

SNOWMASS 2023 (US strategy)

- Next-Gen SRF via advanced thin films & innovative materials (Valente-Feliciano et al.)
- Nb₃Sn: maturing tech for accelerators + dark-matter / GW / quantum-sensing detectors (Posen et al.)

EXAMPLE

- *Aug 2025: first bulk-Nb cavity coated with Nb₃Sn (Cockcroft/ASTeC), RF-tested at HZB*

NEAR-TERM (1-3 yrs):

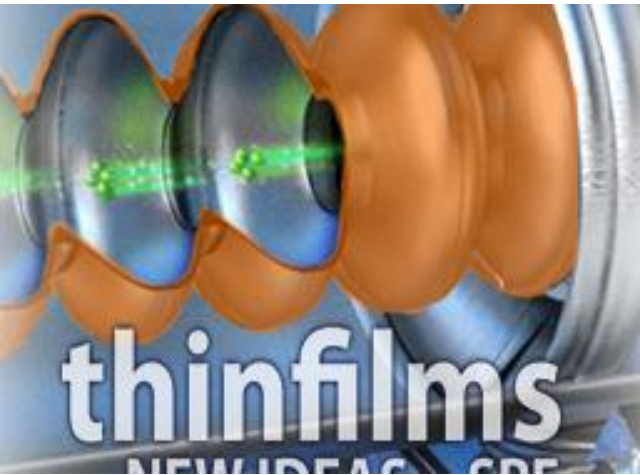
- Improve Nb₃Sn reproducibility via HiPIMS & process control
- Multi-cell Nb₃Sn cavity demonstrations
- Recoating/healing protocols

MID-TERM (3-7 yrs):

- Nb₃Sn production qualification for a real accelerator
- SIS multilayer cavity-scale proof-of-principle

LONG-TERM (7+ yrs):

- Thin-film baseline for FCC, muon colliders, ILC upgrades
- 4.2 K operation as standard -> major cryogenic cost reduction
- Milestone: 12th Int'l Workshop on Thin Films & RF Superconductivity — Chester UK, Sept 2026



Take-Home Message

Thin-film SRF has moved from concept to demonstrated prototype.

The science works. The remaining battle is engineering: reproducibility, defect control, mechanical robustness, and scaling to production cavities. Nb₃Sn is the material to watch; the next 3-5 years will decide whether thin films become the future of SRF.

Thank you